PHOTONIC Silicon Photodiode, Filter Combination Photovoltaic (center wavelength 680 nm) Type PDR-V468 DETECTORS INC. PACKAGE DIMENSIONS INCH [mm] ACTIVE AREA SURFACE 0.365 [9.27] 0.355 [9.02] DIA COVERING ± 0.005 [0.13] 0.080 [2.03]

0.345 [8.76]

0.245 [6.22] 1.235 [5.97] DIA

0.330 [8.38] 0.320 [8.13] DIA

0.123 [3.12]

ACTIVE AREA

- 0.235 [5.97] ACTIVE AREA = 17.74 mm²

FILTER CAP SUBASSEMBLY

CTIVE AREA 0.223 [5.66]



FEATURES

- High transmission
- 10⁻⁴ rejection
- +/- 2nm CWL



0.135 [3.43]

The PDR-V468 is a silicon, PIN planar diffused, photodiode with a narrow band interferance filter. The detector filter combination has a narrow 10 nm half bandwidth designed for low noise photovoltaic applica-

APPLICATIONS

Spectrophotometry

0.200 [5.08] DIA PIN CIRCLE

CATHODE

TO-5 CAN PACKAGE

(CASE GROUND)

ANODE

500 [12.70]

0.020 [0.51] DIA 2 PLACES

0.035 [0.89]

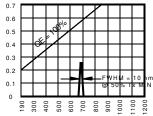
0.425 [10.80]

- Chemistry instrumentation
- Liquid chromatography

tions. Packaged in a TO-5 metal can. ABSOLUTE MAXIMUM RATING (TA=25°C unless otherwise noted)

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	SYMBOL	PARAMETER	MIN	MAX	UNITS	Ś
VBR Reverse V		Reverse Voltage		100	V	K (P
	T _{stg}	Storage Temperature	-20	+85	°C	L L
To Operating		Operating Temperature Range	-15	+70	°C	ISNO
	Ts	Ts Soldering Temperature*		+240	°C	SPC
	I Light Current			0.5	mA	Ë

SPECTRAL RESPONSE



WAVELENGTH (nm)

*1/16 inch from case for 3 secs max

ELECTRO-OPTICAL CHARACTERISTICS (TA=25°C unless otherwise noted)

SYMBOL	CHARACTERISTIC	TEST CONDITIONS	MIN	TYP	MAX	UNITS
lsc	Short Circuit Current***	H = 100 fc, 2850 K	150	200		μA
ΙD	Dark Current	H = 0, V _R = 10 mV		10	50	pА
Rsh	Shunt Resistance	H = 0, V _R = 10 mV	.20	2		GΩ
TC Rsh	RsH Temp. Coefficient	H = 0, V _R = 10 mV		-8		% / °C
CJ	Junction Capacitance	H = 0, V _R = 10 V ^{**}		1700		pF
CWL	Center Wavelength	(CWL, λ o) +/- 2 nm		680		nm
HBW	Half Bandwidth	(FWHM)		10		nm
VBR	Breakdown Voltage	I = 10 µµA	50	75		V
N EP	Noise Equivalent Power	V _R = 10 mV @ Peak		9x10 ⁻¹⁵		W/ \sqrt{Hz}
tr	Response Time	$RL = 1 \ K\Omega \ V_R = 10 \ V$		1.0		μS

Information in this technical data sheet is believed to be correct and reliable. However, no responsibility is assumed for possible inaccuracies or omission. Specifications are subject to change without notice.**f = 1 MHz, ***without filter [FORM NO. 100-PDR-V468 REV A]